L 31977-66

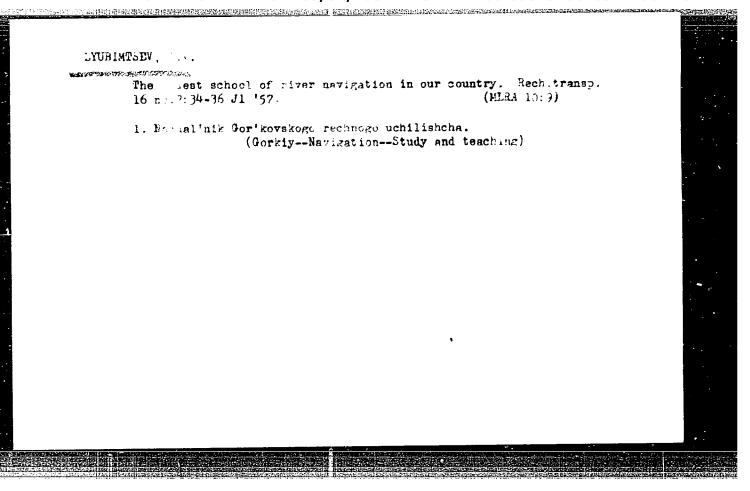
ACC NR, AP6010786

12-108 kc, 312--552 kc, and 612--2044 kc. A few block diagrams illustrate the patterns of conversion channels used in this equipment. In the development of the above equipment, "the leading part was played by C. G. Borodzyuk, A. A. Leshchinskiy, A. A. Livovich, M. S. Orliyevskiy, O. I. Astashkinā, A. G. Merkulov, N. M. Driatskiy, V. N. Babkova, Ye. V. Shimyavich, T. A. Shcheglova, N. G. Myakochina, M. I. Shteyn, Z. A. Gertsik, A. I. Shovkunenko, A. V. Nikishina, I. Yu. Mirimova, and others."

Orig. art. has: 14 figures and 1 tablo.

SUB CODE: 17, 09 / SUBM DATE: 07Sep65

LYUBIMTSEV, I. School of merchant seamen on the Volga; 75th anniversary of the I.P.Kulibin school in Gorkiy. Rech.transp. 22 no.1:20-21 Ja '63. (MIRA 16:2) 1. Nachal'nik Gor'kovskogo rechnogo uchilishcha. (Gorkiy...Nautical training schools)



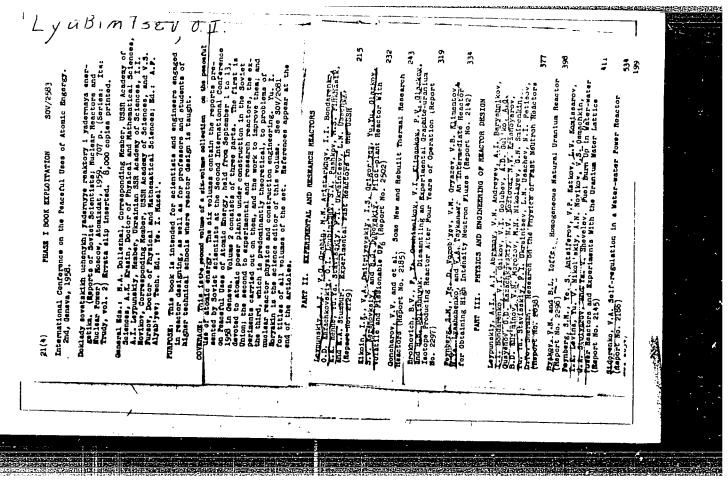
XUZNETSOV, V.A.; ZAGAYNOVA, L.S.; LOGINOVA, N.P.; LYUBINTSEVA, I.Ya.;
ONOPRIYENKO, N.S.; TSIMEAL, L.Ye.

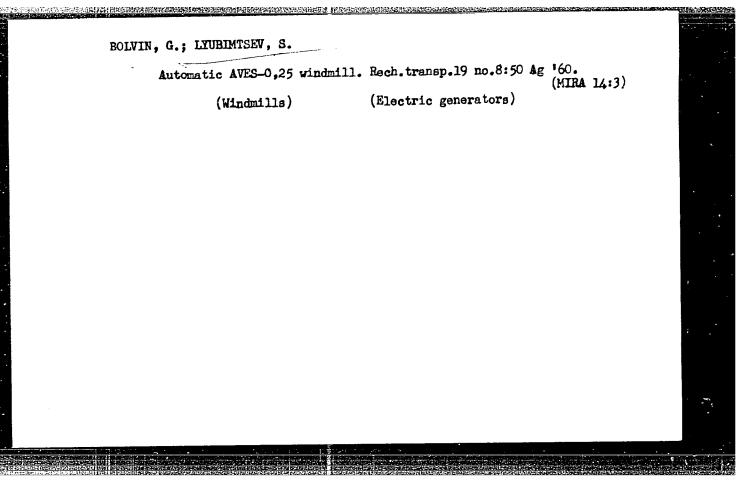
Contact differences of potential between certain liquid metals and their alloys. Dokl.AN SSSR 138 no.1:156-158 My-Je °61.

(MIRA 14:4)

1. Ural'skiy gosudarstvennyy universitet im. A.M.Gor'kogo.
Predstavleno akademit co A.N.Frumkinym.

(Electromotive force) (Liquid metala)





fituritisty, S. A., Kiminskiy, L. Yu.

Conveying Nachinery

Somiautomatic single-bray conveyor for patt no aciti na in reparatory stags. Leg.
grow, 12, No. 7, 1952.

9. Monthly List of Russian Accessions, Library of Congress, November 1953/ Unclassified.

APPROVED FOR RELEASE: 08/31/2001 CIA-RDP86-00513R001031210017-5"

SUBJECT:

USSR/Food Made from Sawdust

25-6-13/46

AUTHOR:

Lyubimtsev, V., Engineer

TITLE:

Fodder Made from Sawdust (Korm iz drevesnykh opilok)

PERIODICAL: Nauka i Zhizn' - June 1957, #6, p 28 (USSR)

ABSTRACT:

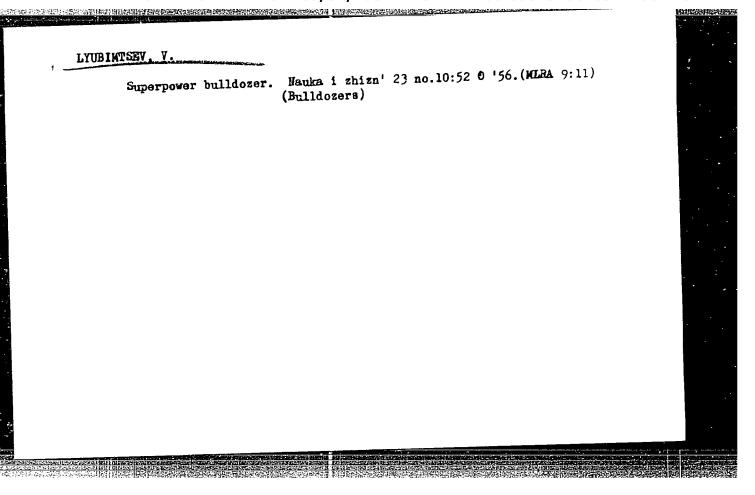
A new field in the use of atomic energy may become the production of fodder derived from sawdust after exposing it to radioactive radiation. Experiments to that effect were conducted in the USA. Sawdust consists of 60 % carbohydrates, mainly in the form of cellulose. Since the gastric juice in a ruminant's stomach can convert only small quantities of it into sugar, scientists think that by exposing the sawdust to redicactive radiation it may be converted to a product that could be easily assimilated by cattle. Experiments have shown that 2/3 of the cellulose exposed to beta rays could be "digested" after having been placed in an artificial "stomach" filled with gastric juice of animals. Experiments with cattle will have to prove if the method is of any practical use.

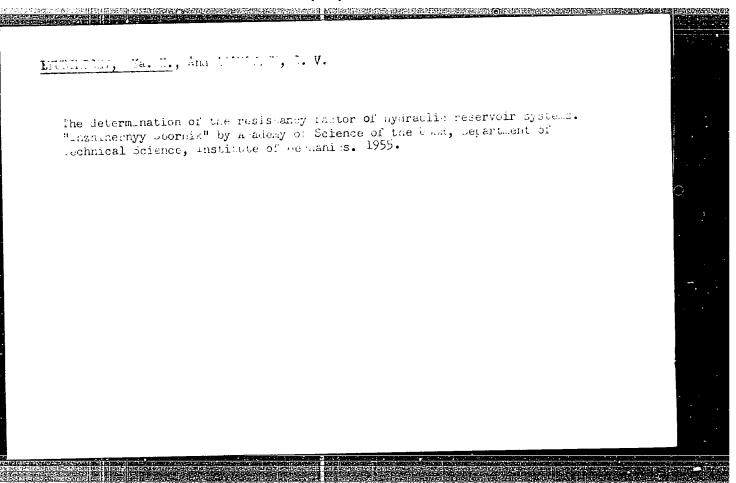
Card 1/2

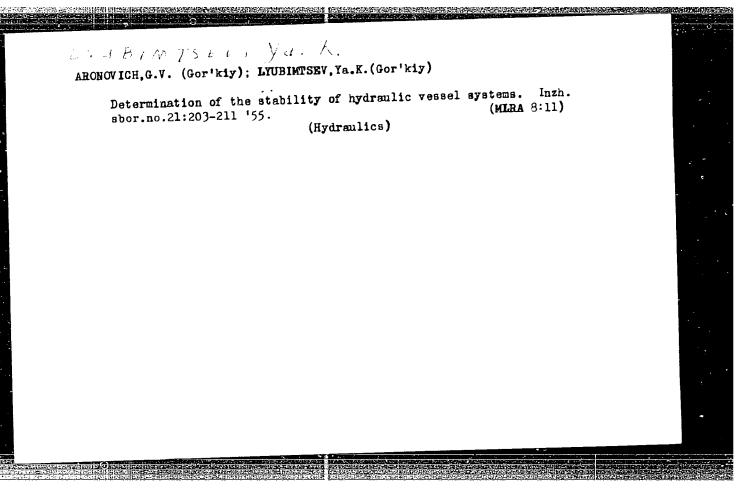
APPROVED FOR RELEASE: 08/31/2001 CIA-RDP86-00513R001031210017-5"

TITLE: Fodder Made from Sawdust (Korm iz drevesnykh opilok)

ASSOCIATION: PRESENTED BY:SUBMITTED:
AVAILABLE: At the Library of Congress
Card 2/2







APPROVED FOR RELEASE: 08/31/2001 CIA-RDP86-00513R001031210017-5"

AUTHOR:

LYUBIMTSEV, YA. K., GOR'KIY

PA - 2191

TITLE:

The conditions for the Stability of the Steady Modes of Operation of a Hydro-Electric Plant with a Differential Belancing Reservoir. (Usloviya ustoychivosti statsionarnykh rezhimov GES

s differentsial'nym uravnilel'nym reservuarom, Russian) Izvestiia Akad. Nauk SSSR, Otdel. Tekhn, 1957, Vol , Nr .

PERIODICAL:

pp 48-56 (U.S.S.R.) Received: 3 / 1957

Reviewed: 4 / 13

ABSTRACT:

By means of a second method developed by LYAPUNOV, satisfactory conditions for the stability of the steady modes of operation of hydro-electric plants with a differential balancing reservoir the case of finite fluctuations are set up (lack of a counter current in the pressure penstock and neglect of water inertia 15 the reservoir) Besides, the correctness of the generally assumed (but mathematically not accurately confirmed) criterion for the stability of the system is proved in detail. First, equations for the motion of the system, the equation for untearability, the equation for the relations between the levels and the equation for regulation are written down. Next, the second method by LYAPUNOV is applied and, according to the theorem of SYLVESTER, the three conditions are written down in order that the quadratic form of the derived equation be positively determined. The first derivation of the function V by LYAPUNOV is found. In order to determine

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APPROVED FOR RELEASE: 08/31/2001 CIA-RDP86-00513R001031210017-5"

PA - 2191

The Conditions for the Stability of the Steady Modes of Operation of a mydro-Electric Plant with a Differential Balancing Reservoir.

the domain of stability, a surface $V^*=0$ is constructed and only that part is taken into account where $V^*=0$. Such a domain really exists and comprises the point 0. Confining oneself to dealing only with nonlinearity in the aforementioned system of equations, the derivation V is simplified. This can also be ascertained according to the method developed by LUR'E and LETOV. (2 illustrations)

ASSOCIATION:

Research Institute for Technical Physics at Gorkiy

PRESENTED BY:

SUBMITTED:

14.8.1956

AVAILABLE:

Library of Congress

Card 2/2

EMURIMISEV, Ya. K.: Master Phys-Math Soi (diss) -- "The stability of stationary operation of hydroelectric power plants with differential equalizing reservoirs, and with n cylindrical reservoirs". Gor'kky, 1986. 4 pp (Gor'kky Res Phys-Tech Inst GIFTI of the Gor'kky State V im N. I. Inbachevskip), 100 copies (KL, No 6, 1999, 124)

APPROVED FOR RELEASE: 08/31/2001 CIA-RDP86-00513R001031210017-5"

06519 SOV/141-58-1-9/14

AUTHOR: Lyubimtsev, Ya. K.

TITLE: Conditions Sufficient for the Overall Stability of a System

of n Hydraulic Reservoirs

PERIODICAL: Izvestiya vysshikh uchebnykh zavedeniy, Radiofizika, 1958, Nr 1, pp 96-105 (USSR)

ABSTRACT: A system for feeding a turbine is assumed to consist of a reservoir having a constant level and n equalizing reservoirs, all of them being connected by a common shaft; the first n - 1 reservoirs contain lumped resistances (see the figure). It is necessary to determine the conditions sufficient for the overall stability of the system under the assumption that all the elements of the systems are defined and that its output power is constant. The operation of the system can be described by Eqs (1.1), while the condition of the constant power output is described by Eq (1.2). The symbols in Eqs(1.1) are explained in the figure. The additional symbols are as follows: z is the height of the level in the i-th equalizing reservoir, Q is the outflow of the liquid, v; is the

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Conditions Sufficient for the Overall Stability of a System of n Hydraulic Reservoirs

velocity of flow and $P_iv_i^2$ is the loss of pressure in the i-th portion of the hydraulic system. The symbol O corresponds to a new equilibrium regime. If it is assumed that v>0 and if the condition (1.2) is combined with Eqs (1.1), the system of differential equations can be written as Eqs (1.3). In this the notation defined by Eqs (1.4) is adopted. Now, instead of Eqs (1.3) , a system of perturbation equations is constructed in such a way that $y_i = y_{i0} + u_i$ and $x_i = x_{i0} + \begin{cases} i \end{cases}$, where y_{i0} and x_{i0} can be found from the equilibrium condition and are given by Eqs (1.5). The perturbation equations are written as Eqs (1.6). The system is first analyzed for the case when the reservoirs do not contain any resistances, which is equivalent to $k_1' = 0$. The conditions of stability for the system can be found by the second Lyapunov method. The Lyapunov function is given by Eq (2.1). The coefficients of Eq (2.1) should satisfy 2n-1 conditions which are expressed by Eqs (2.3). Secondly, they should satisfy the conditions expressed by Eqs (2.4). The derivative of the Lyapunov function can therefore be expressed

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06519 SOV/141-58-1-9/14

Conditions Sufficient for the Overall Stability of a System of $\,$ n $\,$ Hydraulic Reservoirs

as Eq (2.5). In a system with n=1, the conditions (2.3) and (2.4) can be represented by Eq (3.1). The Lyapunov function is given by Eq (3.2) and the conditions of stability are expressed by Eqs (3.4). If the n-1 equalizing reservoirs contain lumped resistances, the derivative of the Lyapunov function is given by Eq (4.1) where v_0 is identical with

Eq (2.5). The equation can be employed to investigate a system consisting of two reservoirs, the first of which contains a resistance. The coefficients of the Lyapunov function for this case are expressed by the first equations on p 104. The system in which at least $y_i < 1$ is

also considered. In this case the basic formulae are written as Eqs (5.3), while the derivative of the Lyapunov function is given by Eq (5.3). The author expresses his gratitude to

Card 3/4

APPROVED FOR RELEASE: 08/31/2001 CIA-RDP86-00513R001031210017-5"

06519 SOV/141-58-1-9/14

Conditions Sufficient for the Overall Stability of a System of n Hydraulic Reservoirs

G. V. Aronovich and N. A. Kartvelishvili for a number of valuable remarks. The paper contains 1 figure and 4 Soviet references.

ASSOCIATION: Issledovatel'skiy fiziko-tekhnicheskiy institut pri Gor'kovskom universitete (Physics Engineering Research Institute of Gor'kiy University)

SUBMITTED: April 21, 1957.

Card 4/4

LYUBINTSEV, Ya.K. Stability of stationary conditions in hydroelectric power stations equipped with a differential compensating reservoir. Izv.vys.ucheb. zav.; radiofiz. 1 no.2:187-190 '58. (MIRA 11:11) 1. Issledovatel'skiy fiziko-tekhnicheskiy institut pri Gor'kovskom universitete. (Hydraulics)

ARONOVICH, G.V.; LYUBIATSEV, Ya.K. Effect of water inertia in a turbine pipe system on the operational stability of hydroelectric power plants with regulating reservoirs. Izv.vys.ucheb.zav.; radiofiz. 3 no.3:538-540 '60. (MIRA 13:8)

1. Nauchno-issledovatel skiy fiziko-tekhnicheskiy institut pri Gor'kovskom universitete.

(Hydroelectric power stations)

ARONOVICH, G.V.; BELYUSTINA, L.N.; KARTVELISHVILI, N.A.; LYUBIMTSEV, Ya.K.

Problems of the stability of stationary operating conditions of hydroelectric generating stations and power systems viewed as problems of the theory of oscillations. PMTF no.3:56-73 S-0 '61. (MIRA 14:8)

(Hydroelectric power stations) (Oscillations)

LYUBIMTSEV, YA. K., ARONOVICH, V. V., BELYESTINA, I. N. and BALTVELICHVILI, N. A.

"Application of oscillatory system analysis to stability problems in the steady-state operation of hydroelectric stations and jower system."

Paper presented at the Intl. Symposium on Bonlinear Vibrations, Kiev, USSA, 9-19 Sep 61

Research Institute of Technical Physics, Sorky State University, Sorky

SHEYN, T.I., nauchnyy sotrudnik; LYUBIMTSEVA, G.P., nauchnyy sotrudnik

Effect of loads at high temperatures on the characteristics of enant fibers. Tekst.prom. 23 no.11:90-94 N '63. (MIRA 17:1)

1. Vsesoyuznyy nauchno-issledov: el'skiy institut iskusstvennogo volokna.

ACCESSION	NR: AP5020973		007/008/1447/1451	52
AUTHOR: SI	neyn, T. I.; Kudryavt	sev, G. I.; Lyubimts	seva, G. P. 44	29 B
TITLE: Synt	thesis and investigation in the same in th	on of fiber-forming p	16.44	
	ysokomolekulyarnyye		no. 8, 1965, 1447-1	451
	S: synthetic fiber, po		d, polycondensation,	
ABSTRACT	: Conditions for the s	ynthesis and some pre- bis-methylamine(I)	and adipic acid (11) v	vere
by prelimin	Two-stage polycond ary polycondensation ider a nitrogen atmos	of equimolar amount phere. after which t	s of I and II in a seal he container was ope	ned and
the polycone	densation completed.	A temperature of 25 nide suitable for fibe	BOC for the solid phase or drawing. 260C was corporated, in which	e too

L 00751-66

ACCESSION NR: AP5020973

elastic polymer could also be drawn. The addition of a thermostabilizer (di- β naphthyl-p-phenylenediamin'e) had little effect on the final polycondensation rate but gave products with high molecular weights. Physico-mechanical, physico chemical and thermo mechanical properties of polyamide fibers made under model conditions were determined. The fibers made from I and II were superior to those of caprone the melting temperature was higher (341-342C) and the modulus of elasticity and the thermomechanical properties were better. "The trans-TsGMA (1, 4-cyclohexane-bis-methylamine) we, used was synthesized first in the ICKh AN SSSR, faboratory by L. Kh. Freydlin and T. A. Sladkov and then by M. I. Yakushkin and L. I. Gal'perin in the VNIINeftekhimicheskikh protsessov and was kindly supplied to us for investigation." Orig. art. has: 2 tables and 3

ASSOCIATION: Vsecoyuznyy nauchno-issledovatel'skiy institut iskusstvennogo volokna(All-State Scientific Research Institute of Artificial Fiber) 44,55 SUB CODE: MT, GC ENCL: 00

SUBMITTED: 02Oct64

OTHER: 002

NR REF SOV: 007

Card 2/2

APPROVED FOR RELEASE: 08/31/2001 CIA-RDP86-00513R001031210017-5"

23815 \$/020/61/138/001/020/023 B101/B231

26.2531

AUTHORS: Kuznetsov, V. A., Zagaynova, L. S., Loginova, N. P.

Lyubimtseva, I. Ya., Onopriyenko, N. S., and Tsimbal, L. Ye

The second secon

TITLE: Contact potential differences between some liquid metals and

their alleys

PERIODICAL: Doklady Akademii nask SSSR, v. 138, no. 1, 1961, 156-158

TEXT: This is to continue the authors' research on contact potential differences between liquid metals and their alloys (ZhFKh, 34, 1349 (1960)). The contact potential differences were determined thermoelectronically by recording the volt-ampere characteristics of a dicde with once the pure metal and then the alloy being used as anose. Based upon the assumption that the contact potential difference is approximately equal to the difference of the zero charge potential and on the grounds that there is a great difference between the zero charge potentials, it appears advantageous to determine the contact potential difference (CPD), particularly between Zn. Cd. Ti. And Bi on the one hand, and their respective alloys with Te on the other. Difficulties that arose were due

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23815

S/020/61/138/001/020/023 B101/B231

Contact potential difference in the heart

to the fact that To and Id have an excessively high vapor pressure and that a number of these metals, in lister of Bi, form compounds with Te The contact potential difference was, therefore, determined: 1) for Sn and Sn-T1 alloy (23.8 % T.) (Fig. 1); 2) for T1 and T1-Sn alloy (49.8 % Sn) and on-it alloy (2780 70 in The alloy 50.5 % Te, (Fig. 26); 4) for Bi and (Fig. 2A); 3) for Tl and Ti-T- alloy 50.5 % Te, Bi-Te alleys (3.6 % Te and 9 % Te) B. and Sn were to be filled mong the purity class 8-3 (V-3); The contained about 0.02 % of Fe. Pb. and Cd impurities (spectrostopically determined by Ro Jutkina) Te was twice distilled in a vacuum. All the measurements were made at a temperature of 450°C. The method applied was less read in the above-mentioned reference Results; for Sn/Sn - Ti CFD - C.13 v; for Tl/Tl · Sr CPD = 0 25 v; for T1/T1 + Te CPD = 0.65 "; f r B./B: -T- JPD = 0.3 and 0.35 ". respectively Fig. 3 shows the zero tharge potentials for Sn-Te alloys as a function of their composition. This implies that the CPD between the metals and their alloys under consideration is case to the difference of the zero charge potentials, which has proved to be valid also for Bi/Bi +Te (difference of zero charge potential with 3 5 % Te equal to 0.25 v, with 9 % Te equal to 0.33 v) The fact that the volv-ampere characteristics of Tl-Sn, Tl-Te, and Bi-Te alloys are shifted in positive direction indicates that the work

Card 2/6 3

S/02C/61/138/301/02C/CT)

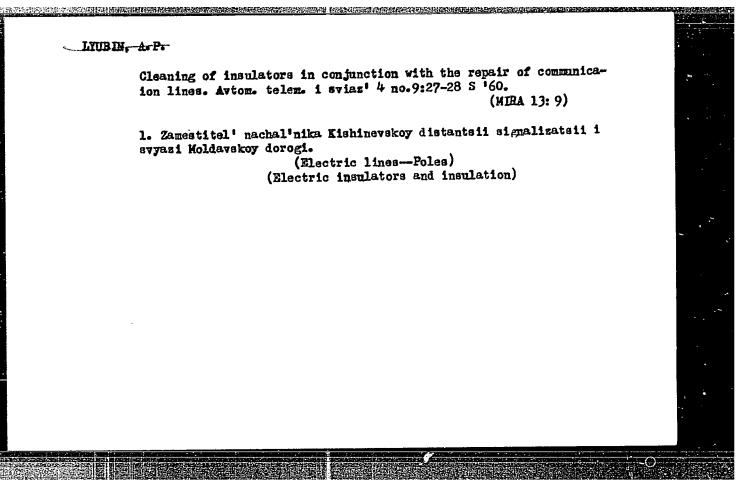
Contact potential differences between... B101/323*

function in these alloys is greater than in pure metal. In conformity with the zero charge potential difference (Fig. 3), Sn-Tl alloy about the opposite effect. The authors thank Academician A. N. Frumin for discussion. There are 4 figures and 5 references: 4 Soviet-bloc and 1 non-Soviet-bloc.

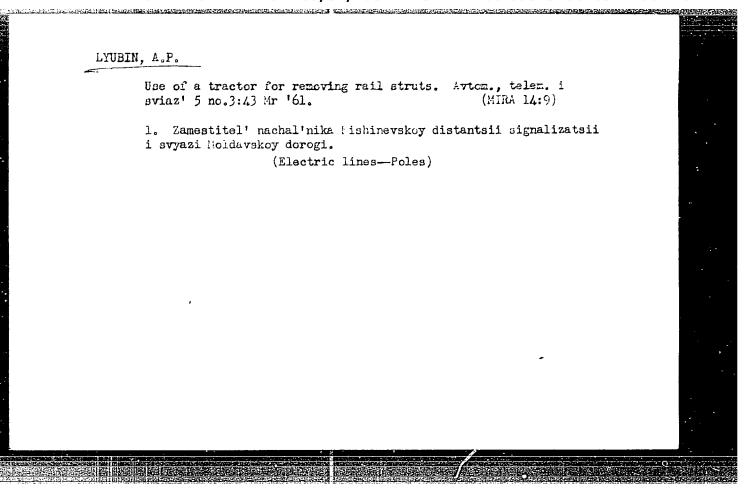
ASSOCIATION: Ural'skiy gosudarstvennyy universitet im. A. M. Gor'koro (Ural State University im. A. M. Gor'kiy)

PRESENTED: December 10, 1960, by A. N. Frunkin, Academician

SUBMITTED: November 25, 1960.



Combating interference caused by static charges. Avtom., telem i sviaz' 4 no.10:30-31 0 '60. (MIRA 13:10) 1. Zamestitel' nachal'nika Kishinevskoy distantsii signalizatsii i svyazi Moldavskoy dorogi. (Railroads--Communication systems)



LYUBIN, A.P.

Reception of railroad communication broadcasts at intermittent stations. Avtom., telem. i sviaz! 5 no.6:39 Je '61. (MIRA 14:9)

l. Zamestitel' nachal'nika Kishinevskoy distantsii signalizatsii i svyazi Moldavskoy dorogi.

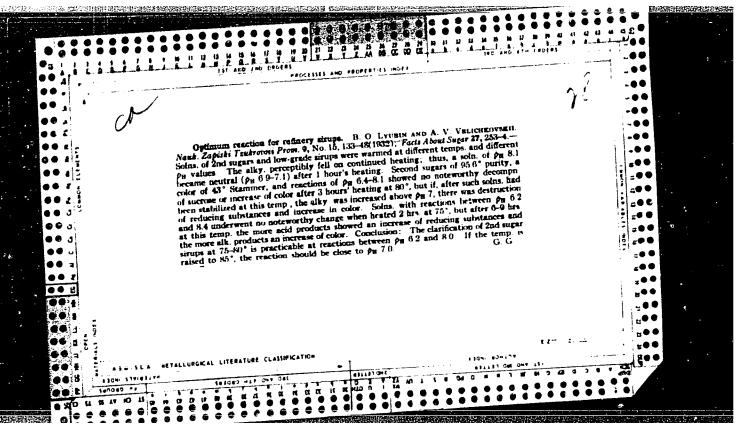
(Railroads—Communication systems)

RUMYANTSEV, P.K.; RYZHKOV, M.S.; AIEKSEYEV, P.A.; IVANOV, A.I.; TAGAN, I.L., elektromekhanik; LYUBIN, A.P.

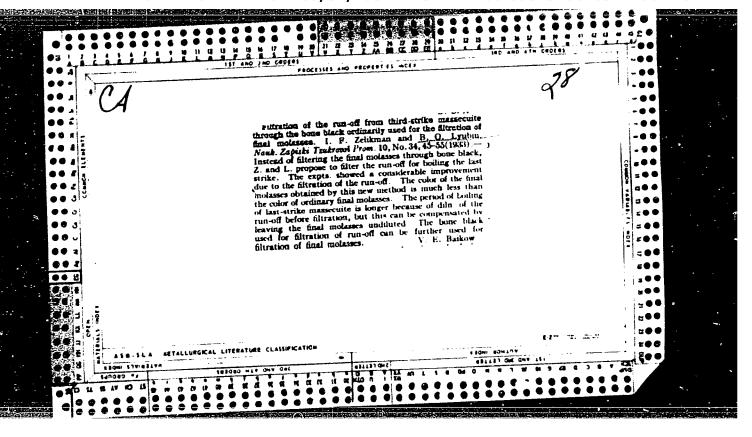
Discussion of the article "Pedal or track circuit." Avtom., telem. 1 sviaz 9 no.10:38-39 0 '65. (MIRA 18:11)

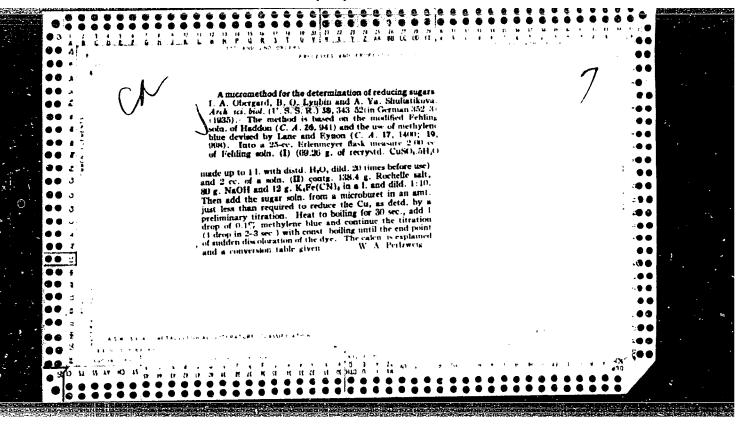
1. Starshiy elektromekhanik Velikolukskoy distantsii Oktyabr'skoy dorogi (for Rumyantsev). 2. Starshiy elektromekhanik Mikun'skoy distantsii Severnoy dorogi (for Ryzhkov). 3. Zemestitel' machal'-nika Nyandomskoy distantsii Severnoy dorogi (for Alekseyev). 4. Glavnyy inzh. Nyandomskoy distantsii Severnoy dorogi (for Ivanev). 5. Krasnolimanskaya distantsiya Donetskoy dorogi (for Tagan). 6. Glavnyy inzh. Kishinevskoy distantsii signalizatsii i svyazi Odessko-Kishinevskoy dorogi (for Lyubin).

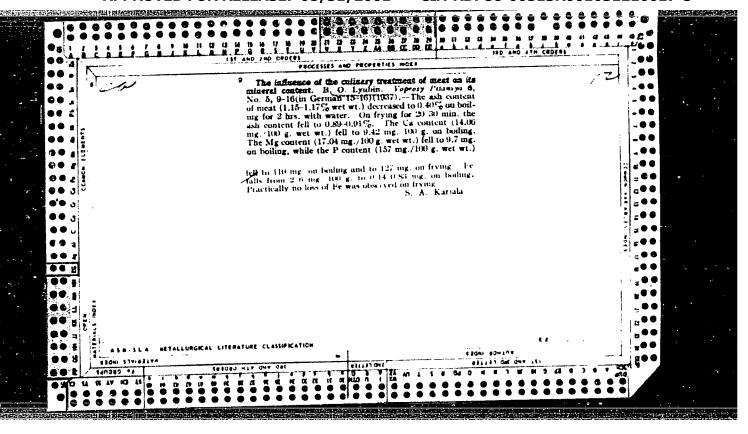
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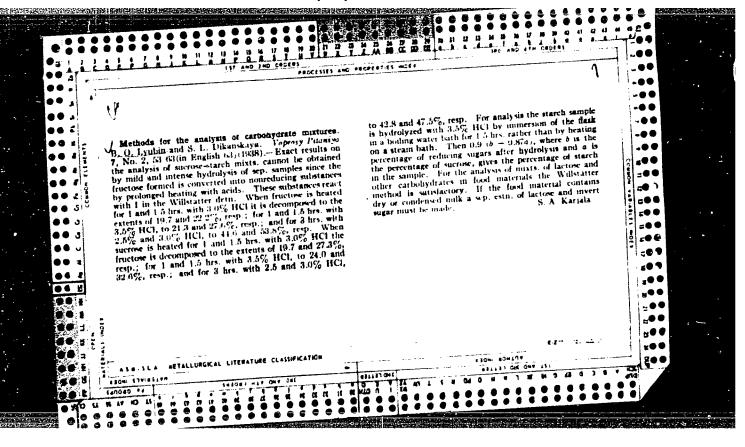


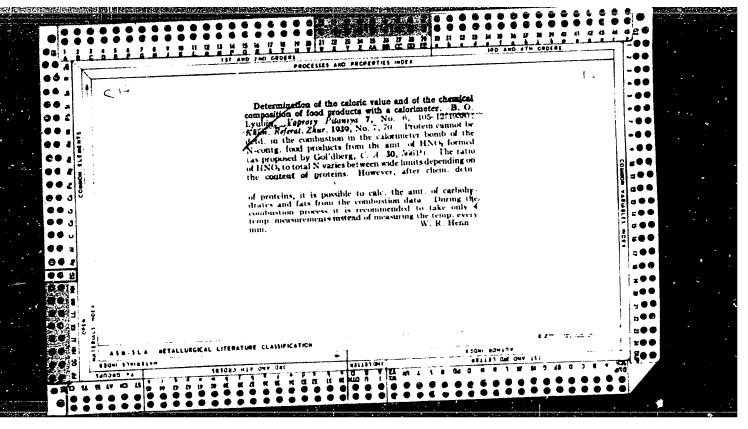
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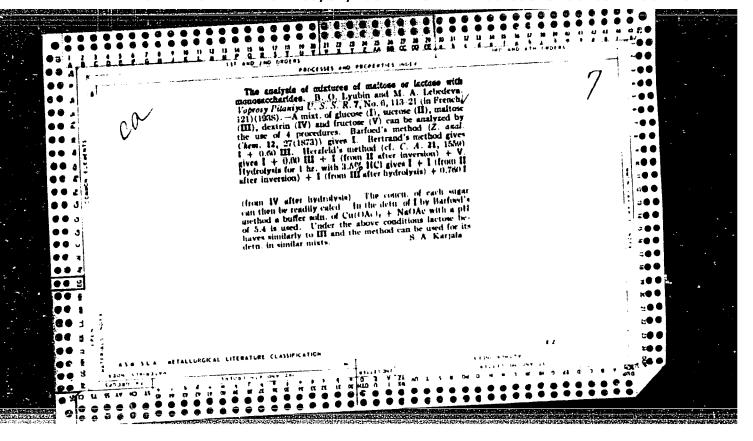


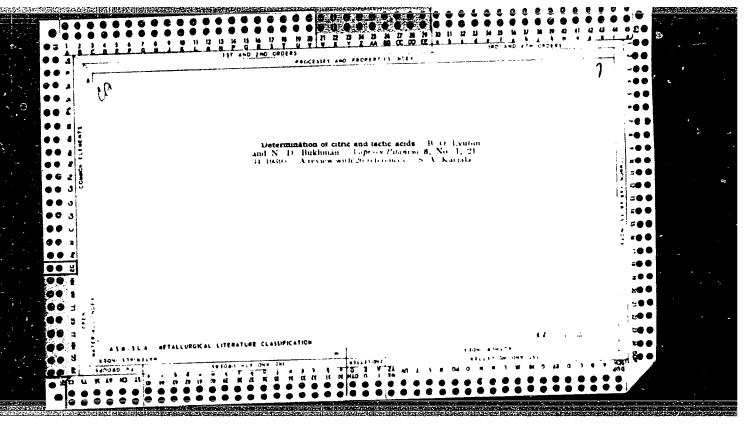


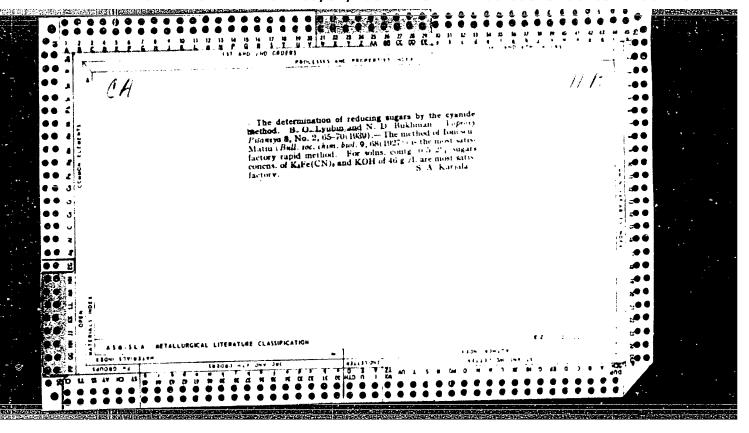


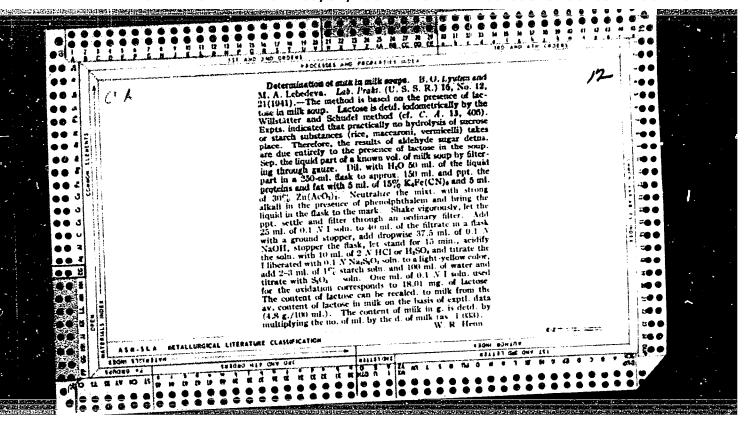


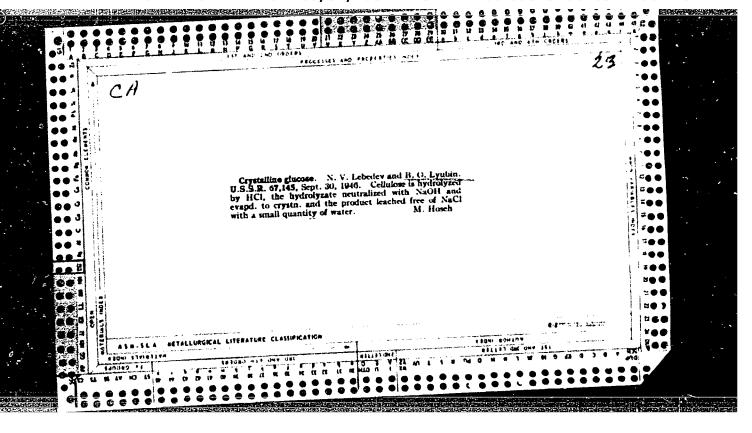










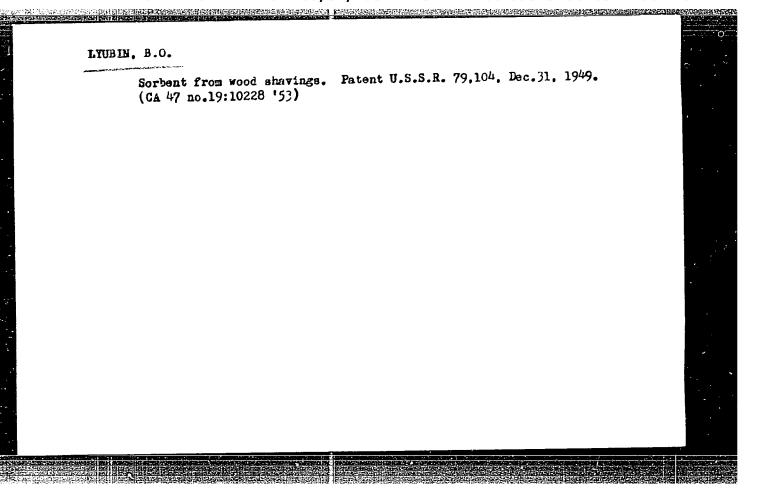


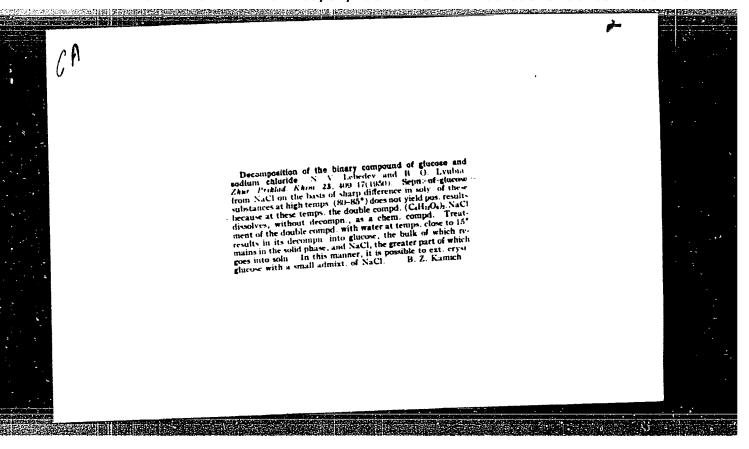
LYUBIN, B. O.

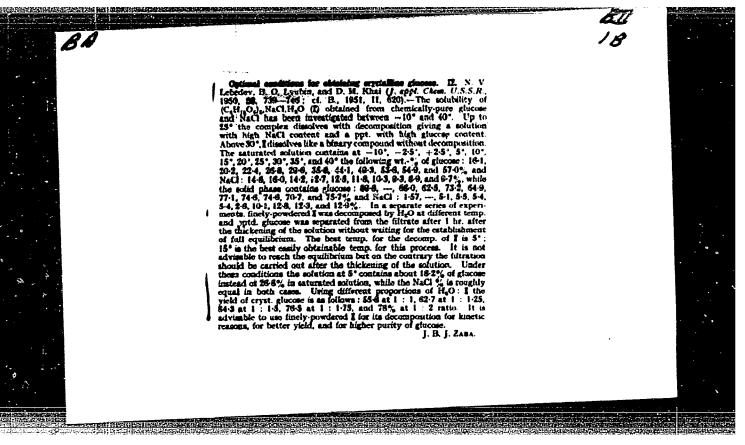
Chemistry.

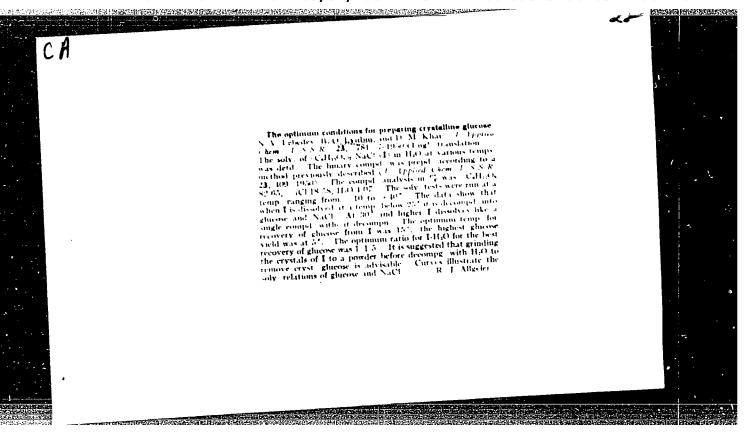
"Method of Determining the Crystallizing Capacity of Mylose Syrups,"

SO: Zhur. Prik. Khim,, 22, No. 2, 1949. Mbr., All-Union Sci. Research Inst. of the Hydrolysis and Sulfide-Alcohol Industry, -c1949-.

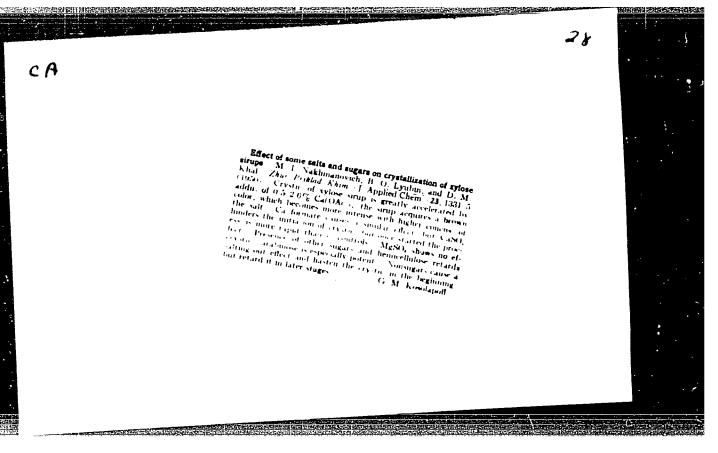


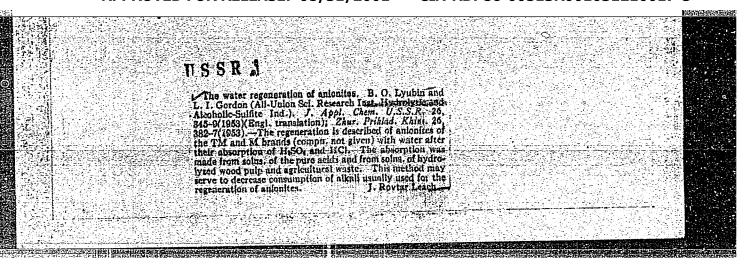




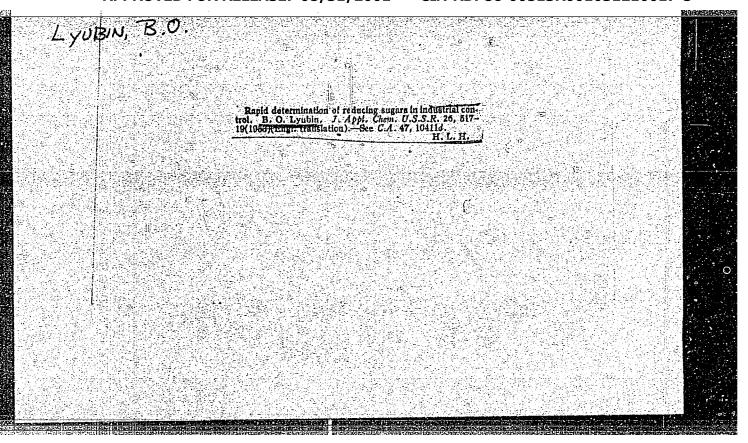


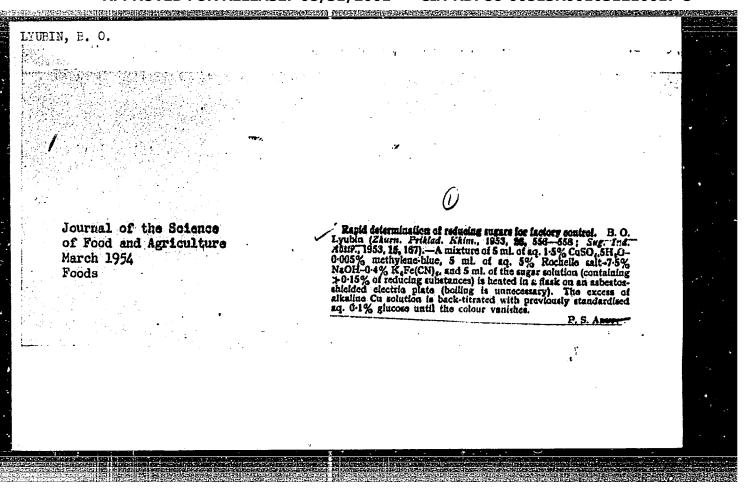
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Teoriya i Prektika Primesiya			
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LYUBIN B. O

CHINA / Chemical Technology. Chemical Products and Their

Application - Carbohydrates and refinement

Abs Jour : Referat Zhur - Khimiya, No 2, 1958, 6130

Author : Lyubin B. O.

Inst : Not given

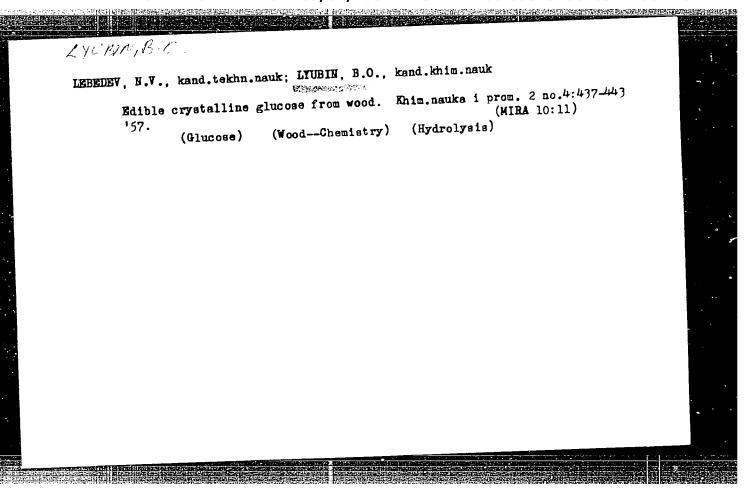
Title : Rapid Method for Determining Reducing Sugars in Production

Control

Orig Pub : Khuasyue shitsze, 1955, No 7, 344

Abstract : A translation. See RZhKhim, 1953, 3535

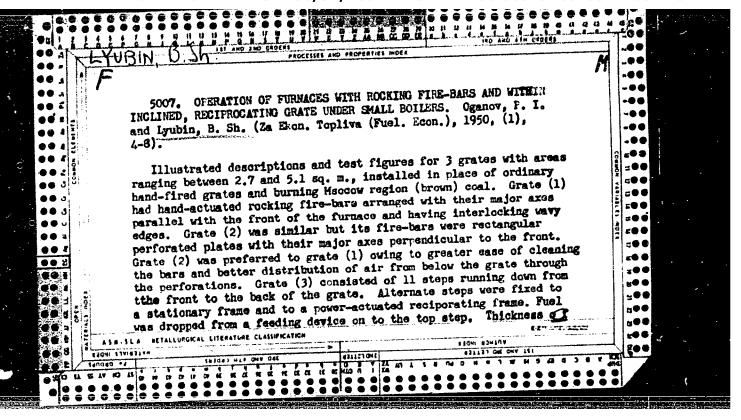
Card 1/1

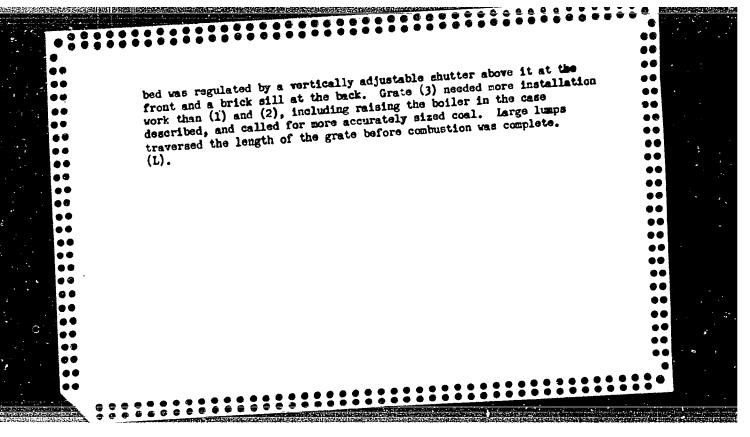


LEBEDEV, N.V.: LYUBIN, B.O.: BANNIKOVA, A.A.

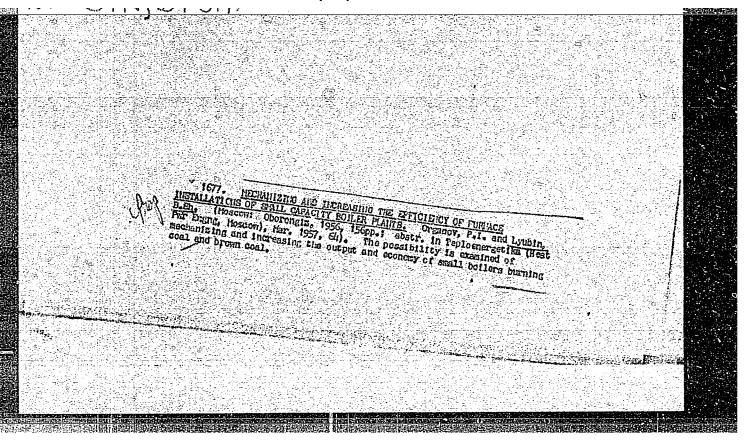
Yield of crystallized glucose in the decomposition of a binary compound of glucose and sodium chloride. Gidroliz. i leachim.prom. 11 no.7:3-5 '58. (MIRA 11:11)

1. Vaesoyuznyy nauchno-isaledovatel'skiy institut gidroliznoy i sul'fitnospirtovoy promyshlennosti. (Glucose) (Crystallization)





"APPROVED FOR RELEASE: 08/31/2001 CIA-RDP86-00513R001031210017-5



LYUBIN, B.Sh., inzh.; SHAPIRO, I.F., inzh.

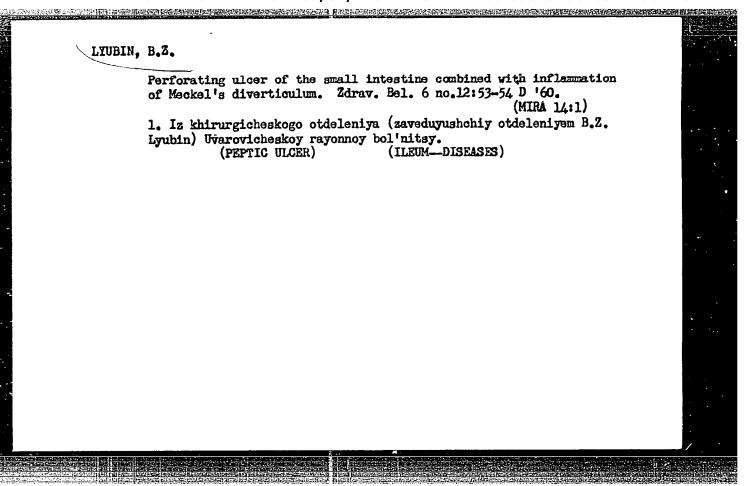
Experience in the adjustment of modernized Shukhov-Berlin boilers.
Prom. energ. 20 no.5:26-29 My '65. (MIRA 18:7)

OGANOV, P.I., inzh.; LYUBIR, B.Sh., inzh.; KATSENELENBOGER, B.V., inzh.;
KRUZHKOV, V.N., inzh.

Experience in the modernization of Shukhov-type boilers operating
on liquid fuel. Prom. energ. 17 no.3:18-23 Mr '62. (MIR. 15:2)
(Boilers)

OGANOV, P.I., inzh.; LYUBIN, B.Sh., inzh.; KATSENELENBOGEN, B.V., inzh.; KRUSHKOV, V.N., inzh.

Modernization of Shukhov-Berlin system boilers operating on liquid and gaseous fuels. Prom. energ. 17 no.8:13-20 Ag *62. (MIRA 16:4) (Boilers)



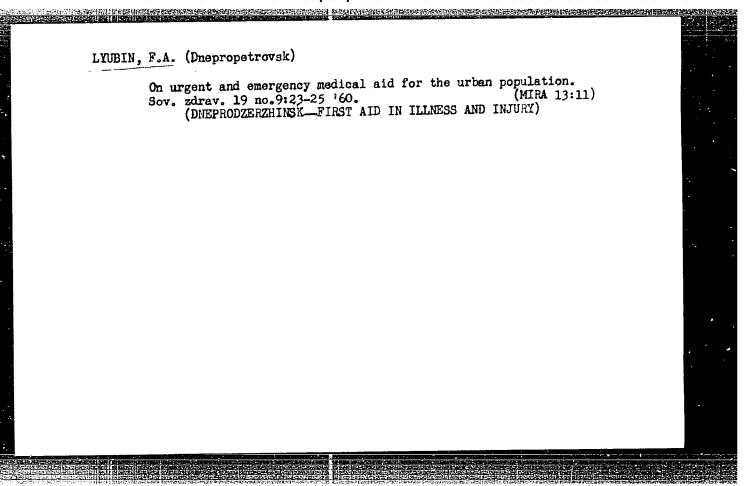
Perforation o Je '61.	of the ileum by a fish bone. Zdrav. Bel. 7 no.6:60 (MInA 15:2)		
l. Iz khirurg B.Z.Lvubin) U	1. Iz khirurgicheskogo otdeleniya (zaveduyushchiy otdeleniyem B.Z.Lyubin) Uvarovicheskoy rayonnoy bol'nitsy (glavnyy vrach M.F.			
Dubitskaya).	(ILEUM_FOREIGN BODIES)			
	· •			
	•			

KOTLYARENKO, B.M.; KASIM, I.M.; LYUBIN, B.2.

Morphological properties of goiter-induced changes in surgically removed thyroid glands as one of the objective indices of the severity of endemic goiter in Gomel' Province. Probl. endok. i gorm. 10 no.1:38-40 Ja-F 164.

(MIRA 17:10)

1. Gomel'skiy oblastnoy protivozobnyy dispanser, 1-ya Sovetskaya oblastnaya bol'nitsa i 4-ya Sovetskaya gorodskaya bol'nitsa Gomel'skoy oblasti.



26 2145 24,430**0** 39222 S/207/62/000/003/001.016 1028/1228

AUTHOR:

Lyubin, L. Ya. and Povitzkiy, A. S. (Moscow)

TITLE:

Motion of gas bubles caused by pressure fluctuations in the liquid in the absence of mass

forces

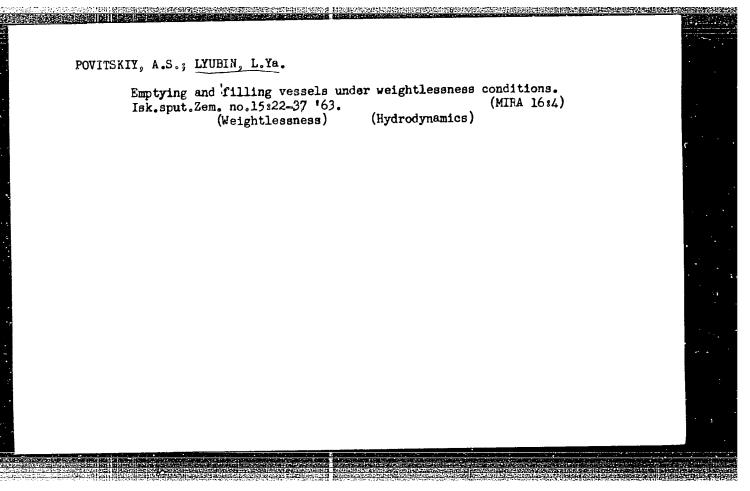
PERIODICAL: Zhurnal prikladnoy mekhaniki i tekhnicheskoy fiziki, no. 3, 1962, 3-9

TEXT: The paper extends the Bjerkness-Zhukovskiy analysis of the force of interaction between fluctuating spheres to the case of motion of gas bubbles caused by pressure fluctuations. The translational motion of two gas bubbles, suspended in a liquid occupying a spherical volume on whose external surface acts a fluctuating pressure p(t), is examined. The Lagrangian equations of motion are integrated for the case $p(t) = p_0 + p \sin mt$ under some simplifying assumptions and neglecting the mass forces. The results obtained are extended to the case of a liquid contained in a vessel of arbitrary shape, and also to the case of an unique bubble placed near the vessel wall. There is 1 figure.

SUBMITTED:

January 30, 1962

Card 1/1



L 392b-66 FSS-2/FWT(1)/EWP(m)/FS(v)-3/EWA(4)/FCS(k)/EWA(1) DD/RD ACC NR. AP5026052 532.529.6

AUTHOR: Povitskiy, A. S.; Lyubin, L. Ya.

TITLE: Gas flow into a liquid under weightlessness conditions

SOURCE: Kosmicheskiye issledovaniya, v. 3, no. 5, 1965, 718-729

TOPIC TACS: hydrodynamics, gas flow, axial flow, weightlessness

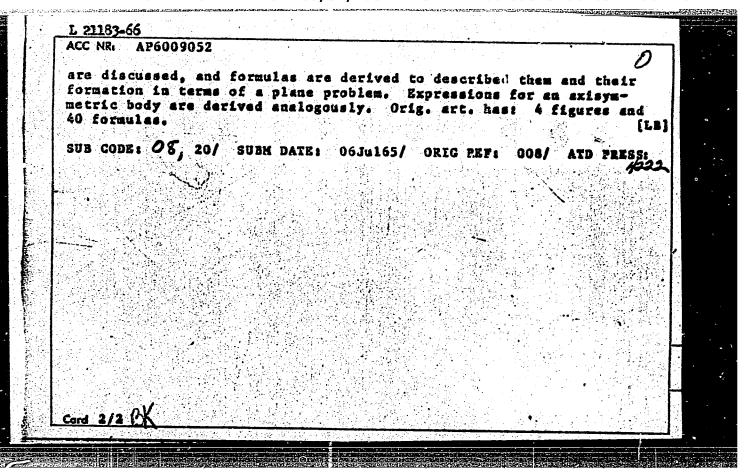
ABSTRACT: The effect of near-zero and zero gravity on the process of bubble formation (bubbling process) in a flow of gas injected into a liquid through a tube is considered. Flows of gas into stationary and moving liquids are analyzed for various values of Bond and Weber numbers under conditions of weightlessness. Conditions are established under which the bubbles may break away from the tube. The main parameter characterizing the process, the ratio D/d where D is the diameter of a bubble at the time of breaking away and d the diameter of the tube, is expressed in terms of the Bond number. The analysis shows that the absence of mass forces and even the unfavorable direction of g forces can be compensated by the motion of the fluid under specific conditions. The interaction between a forming bubble and an already detached bubble, that is, between pulsating and oscillating bubbles in aliquid is evaluated by using Zhukovskiy's method for solving the Bjerknes problem. Orig. art. has: 6 figures and 25 formulas.

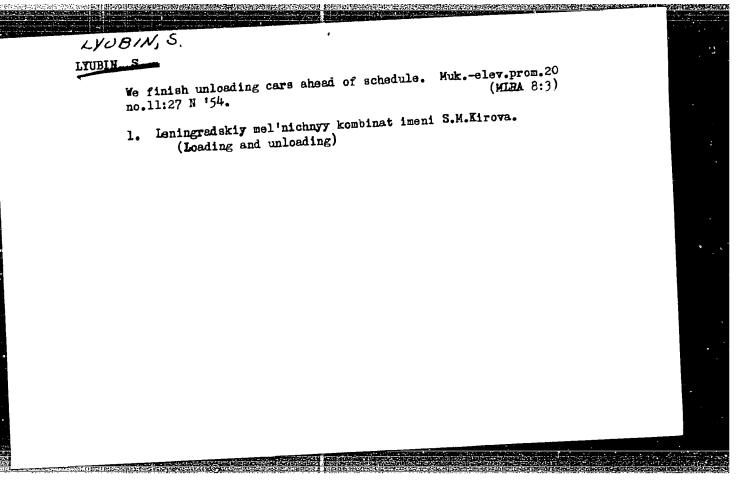
Card 1/2

"APPROVED FOR RELEASE: 08/31/2001 CIA-RDP86-00513R001031210017-5

3921-66 ACC NR: AP5026052 ASSOCIATION: none		
SUBMITTED: 240at64	ENCL: 00	SUB CODE: ME
NO REF SOV: 009	OTHER: 005	ATD PRESS
$\widehat{(a,b)}$		
Card 2/2		

BACK THE STATE OF 21183-66 $\mathbf{E}\mathbf{W}\mathbf{r}(\mathbf{1})$ ACC NRI AP6009052 SOURCE CODE: UR/0207/66/000/001/0083/0092 26 AUTHOR: Lyubin, L. Ye. (Hoscow); Povitskiy, A. B ORG: none TITLE: Oblique impact of a solid body on soil SOURCE: Zhurnal prikladnoy mekhaniki i tekhnicheskoy fiziki, no. 1,4 1966, 83-92 TOPIC TAGS: impact, soil mechanics, soil impact deformation ABSTRACT: The oblique impact on a soil surface of a solid body having a parabolic (plane problem) or paraboloidal (axisymmetric body) forebody is reviewed. The soil is assumed capable of significant density change during compaction and is an elastoplastic medium in which uniaxial deformation is governed by the piecewiselinear law. In the first case considered, it is assumed that before impact the body does not rotate, and during penetration angular acceleration is negligibly small, since the corresponding inertia moment is significantly great. Outlined are five stages into which soil deformation can be divided when the initial-velocity component normal to the soil surface is sufficiently large. Various stages Card 1/2





KOZIN, A.I.; THUMOV, A.F.; SOVENKO, P.S.; YEGOROVA, Ye.I.; AKATNOV.
I.H.; KOLUSHEV, V.I.; PAHASENKO, L.I.; KATS, A.R.; AKSENOV.
T.Te.; LYUBIH, S.G.; SOSHEN, S.Te.; RYABIHIH, M.M.; MEL'HIKOV.
P.N.; KLYUSHINA, L.T.; KUTUZOVA, M.G.; GOLOVNYA, V.S.;
IVANOV, A.F.; SINEV, I.I.

I.A. Danilov; obituary. Muk.-elev. prom. 26 no. 12:26 D '60.
(MIRA 13:12)

(Danilov, Ivan Aleksandrovich, d. 1960)

。 第一个人,我们就是一个人,我们就是一个人,我们就是一个人,我们就是一个人,我们就是一个人,我们就是一个人,我们就是一个人,我们就是一个人,我们就是一个人,我们就

LYUBIN, VM,

CIRCUITS AND CIRCUIT ELEMENTS

"Certain Types of RC Sinusoidal Generators Employing Transistors", by V.M. Lyubin, Elektrosvyaz', No 8, August 1957, pp 20-25.

Several transistorized RC oscillator circuits for sinusoidal voltages are considered, and methods are given for their approximate calculation. A comparison is made of the calculated and measured values of the generation oscillation frequency. Problems of interchangeability of transistors in oscillators are discussed.

Card 1/1

- 15 -

SOV/103-13-2-6/15-Tember of the Society (VIIOR E) AUTHOR: Lyubin, V. M., Regular (loluprovod-RC-tuned Transistor Phase-shift Oscillators TITLE: nikovyye RC-Generatory s Povorotom fazy) Radiotekhnika, 1953, Vol. 13, Er 2, pp. 44 - 50 (USSR) FERIODICAL: Received: April 25, 1958 Here different schemes of semiconductor-RC-generators with ABSTRACT: phase reversal are investigated (povorotom fazy). Formulae for the frequency of generation and the criterion for the amplification are derived. The curves showing the dependence of the relation of the voltage amplification factor on the amplifier - K to the amplification criterion K of the resistance R in the CR-circle of a generator with a semiconductor are given. All the curves have a peak more or less distinct. The relation K $_{\rm u}/{\rm K}$ has its maximum value at average values of R. Moreover it can be seem from the curves that the condition for the generation can be guaranteed with any semiconductor apparatus, but not with any value of R. This ought to be the cause for the fact that the experiments in Card 1/3

APPROVED FOR RELEASE: 08/31/2001 CIA-RDP86-00513R001031210017-5"

SOV/108-13-2-6/15

RC-timed Transistor Phase-shift Oscillators

the construction of a generator of the type investigated here with a semiconductor triode of the former production did not succeed. Equation (10) for the voltage transfer factor is derived and it is shown that in the phase opposition with an RC-circuit, that is in the case that the imaginary part of equation (10) becomes equal to zero, a generation will take place. From this the factor α and then the formula (11) for the generation frequency f and the formula (12) for the amplification criterion K can be derived. In the course of the investigation the following regularities were observed: 1) The maximum generation frequency was remarkably lower than the cutoff frequency of the applied triodes. 2) When using RC-circuit a generation with higher frequencies than under apllication of RC-circuit is obtained. 3) An increase of the amplification factor of the amplifier in the generator (e.g. applying the two-cascade amplifier) always offered the possibility to penetrate into the range of higher frequencies. Thus the upper limit of the range of the working frequencies for the semiconductor generator, as distinguished from the valve--RC-oscillators, must be determined rather by the amplification cascades than by the type of the RC-filter applied. These statements want an additional checking by way of computations

Card 2/3

。 第18章 "我们就是我们的一个人,我们就是我们的一个人,我们就是我们的人,我们就是我们的人,我们就是我们的人,我们就是我们的人,我们就是我们的人,我们就会会

sov/108-13-2-6/15

RC-tuned Transistor Phase-shift Oscillators

and experiments though. Finally it is referred to the fact that when taking the particularity of the triodes in semiconductor generators of the sonic and infrasonic range into consideration it is practical to evaluate the generators from the viewpoint of the stability of their parameters under modifications of working conditions. For this purpose the factor (coefficient) of the potential stability can be introduced. This factor shows the potential possibility of stabilizing the generator parameters. With such a coefficient it is convenient to understand the relation K to K. There are 7 figures, 1 table, and 11 references, 7 of which are Soviet.

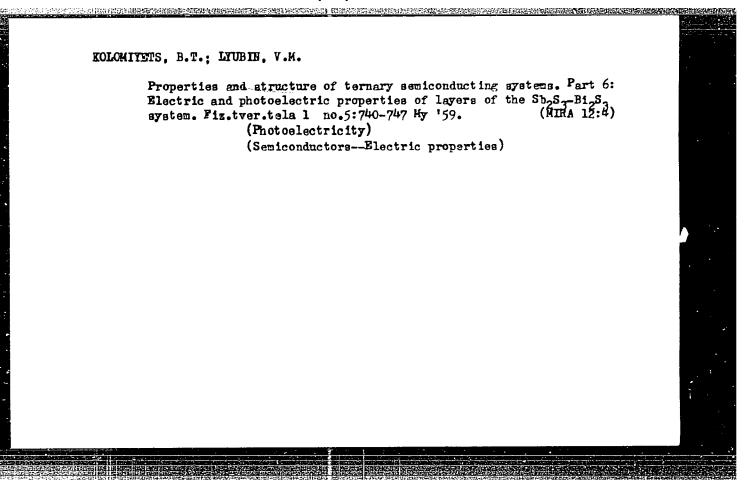
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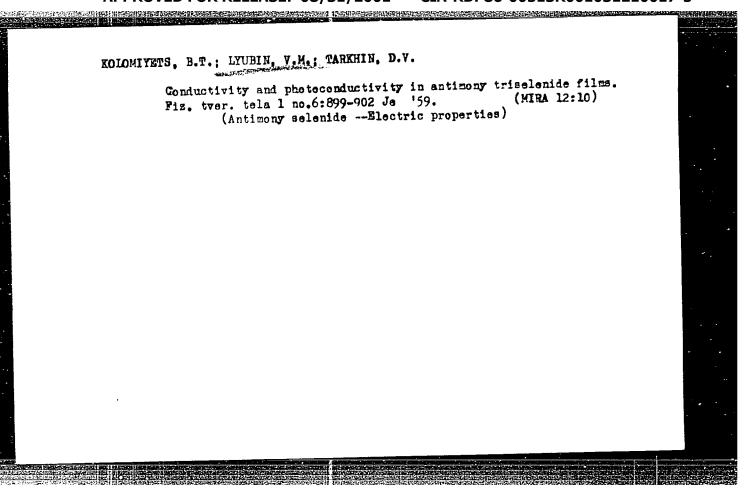
July 8, 1957

Card 3/3

APPROVED FOR RELEASE: 08/31/2001 CIA-RDP86-00513R001031210017-5"

LYUBIN, V. M., Cand Tech Sci (diss) -- "The photoelectric properties of layers of chalcogenides of antimony and arsenic and their use in television transmitting tubes". Leningrad, 1959. 11 pp (Acad Sci USSR, Leningrad Phys-Tech Inst, State Committee of the Council of Ministers USSR on Radio Electronics), 250 copies (KL, No 11, 1960, 133)





SOV/120-59-4-27/50

AUTHOR: Lyubin, V. M.

TITLE: Measurement of the Resistance and Surface Potential in

Semiconductor Layers

PERIODICAL: Pribory i tekhnika eksperimenta, 1959, Nr 4, pp 118-122

(USSR)

ABSTRACT: The resistance R of a high-resistivity semiconductor layer deposited on a conducting surface and irradiated with an electron beam is given by

$$R = \left| U_{S} - U_{D} \right| / I \qquad , \tag{1}$$

where U_s is the surface potential of a layer irradiated with electrons, U_b is the potential of the conducting substrate (base) and I is the current flowing through the layer. It follows that measurement of R involves the determination of the surface potential U_s. The

present paper describes a method which requires two electron beams to measure the surface potential of charged semiconductor

Card 1/5

SOV/120-59-4-27/50

Measurement of the Resistance and Surface Potential in Semiconductor Layers

layers and their transverse resistance for a wide range of U_s (both $U_s > U_b$ and $U_s < U_b$). This method can be also used to study the rate of rise and fall of $U_{\rm S}$ and its distribution across the layer surface. The basis of the method is explained by Fig 1. A semiconductor layer Π deposited on a conducting base, which is called the signal plate C , is subjected to bombardment with two overlapping electron beams produced by two separate electron guns. Secondary electrons knocked out of the semiconductor layer are gathered by a collector K . One electron beam 311 is triggered by short pulses fed to the modulator of its electron gun. The duration and repetition frequency of these pulses are selected in such a way as to minimise charging the semiconductor surface. The other electron beam \mathfrak{H}^2 is used to charge the semiconductor surface. The electron beam M1, acting alone, produces current pulses in the signal-plate circuit, whose polarity and amplitude depend on the voltage U applied to the signal plate, and the collector potential the electron beam current In

Card 2/5

SOV/120-59-4-27/50

HILLS STREET, STREET,

Measurement of the Resistance and Surface Potential in Semiconductor Layers

U_c . Dependence of U_p, the amplitude of pulses in the signal-plate circuit, on U_{sp} is shown in Fig 2 for I = const and U_c = const . For any given value of U_{sp} (e.g. U_{sp} = U) we can find the corresponding value of U_p from the curve of Fig 2. After charging the semiconduct-prises to U" . From Fig 2 we can read off the value of U_{sp} (let us call it U") corresponding to the value of U" . Resistance is then calculated, using Eq (1), where I is the current flowing through the instrument G in Fig 1. This procedure can be repeated for a wide range of magnitudes and polarities of the voltage applied to the semiconductor layers. This method can be used also to

Card 3/5

SOV/120-59-4-27/50

Measurement of the Resistance and Surface Potential in Semiconductor Layers

study the kinetics of rise and fall of $U_{\rm g}$ The instrument used is shown schematically in Fig 3. A bulb 1 contains a conducting plate 2 with a semiconductor layer on it. The conducting plate is in the form of a semi-transparent film (a thin layer of Pt or SnO2) which made it possible to illuminate the semiconductor sample through a glass window 3 (useful in photo-sensitivity studies). Vacuum in the bulb was held at (1-3) x 10-6 mm Hg. The methods of triggering both electronic guns are discussed in detail. The technique employed in amplification, measurement and display of the pulses in the signal-plate circuit is described. The method was used to measure the resistances and photo-sensitivities of Sb2S3, As2Se3, AsSbS3 and amorphous selenium layers. For Sb₂S₃ and amorphous selenium layers the results agreed well with the published data (Refs 2, 8, 10, 13). For As₂Se₃ and AsSbS₃ layers a sharp fall of the resistance was observed on increase of the voltage across the layer. Fig 4 shows the experimental curve

Card 4/5

SOV/120-59-4-27/50

Measurement of the Resistance and Surface Potential in Semiconductor Layers

 $U_p = f(U_{sp})$ for a layer of $\mathrm{Sb}_2\mathrm{S}_3$. Acknowledgment is made to L. N. Dobretsov and A. A. Mostovskiy for their advice. There are 4 figures and 13 references, 7 of which are Soviet, 5 English and 1 German.

SUBMITTED: July 18, 1958.

Card 5/5

SOV/120-59-4-29/50

AUTHORS: Lyubin, V. M., Makedonskiy, V. L.

TITLE: Measurement of the Amplitude of the Pulses Having a Low Repetition

PERIODICAL: Pribory i tekhnika eksperimenta, 1959, Nr 4, pp 125-126 (USSR)

ABSTRACT: The instrument was designed for the investigation of the secondary emission, photo-conductivity and other electric parameters of dielectrics and semiconductors having high resistivity. The circuit of the device is shown in Fig 1. The principal of the operation of the circuit is based on a rapid charging of the storage condenser C₁ which is capable of preserving the charge over a comparatively long time inter-

val; the condenser is then rapidly discharged immediately before the appearance of the next pulse. The pulses to be measured are first amplified in a wideband amplifier (not shown in Fig 1) and applied to the input tube of the circuit in Fig 1, which acts as a phase inverter. The switch K₁ applies positive pulses to the cathode follower which feeds

Card 1/3

SOV/120-59-4-29/50

Measurement of the Amplitude of the Pulses Having a Low Repetition the storage stage. The latter consists of a double triode and the capacitor C_1 as its cathode load. This arrangement permits a rapid charging of C_1 , the charging current being proportional to the amplitude of the pulse. During the appearance of the next pulse, C_1 is rapidly discharged by the thyratron (Fig 1) which is triggered by a narrow pulse corresponding to the leading edge of the measured pulse. The trigger pulses can be formed either by a special circuit or by means of a simple RC differentiating network. The output of the storage capacitor is fed to a cathode-follower bridge circuit where the pulse amplitude is measured by a voltmeter. The device gives a linear inputoutput voltage characteristic for frequencies as low as

Card 2/3

SOV/120-59-4-29/50

Measurement of the Amplitude of the Pulses Having a Low Repetition 1.5 c.p.s. and pulse durations down to 0.5 µsð. This is illustrated in Fig 2. The error of the measurement does not exceed 2-3%. The authors express their gratitude to S. S. Andzhan for valuable advice. There are 2 figures, and 5 Soviet references.

SUBMITTED: July 18, 1958.

Card 3/3

24.2600

AUTHORS:

Kolomiyets, B. T., Lyubin, V. M.

67258 SOV/20-129-4-20/68

TITLE:

Some Specific Features of the Photoelectric Effect in Amorphous

Layers of Arsenic Triselenide

PERIODICAL:

Doklady Akademii nauk SSSR, 1959, Vol 129, Nr 4, pp 789 - 792

(USSR)

ABSTRACT:

The properties of arsenic chalcogenides, i.e. the analogs of antimony have hitherto not been investigated. Publications have so far been giving only very scarce results of investigations of the crystalline layers of As₂Se₃. The present article describes the first results obtained by investigating the substances of this group, which were found on arsenic triselenide layers. The As₂Se₃ was synthetized from elements having the following purity degrees: Se 99.998%, As 99.99...%. The layer was produced by vaporizing in a vacuum at a pressure of p = 10⁻⁵ to 10⁻⁶ mm Hg onto polished glass bases (which have previously partly been coated with a semitransparent conductive film of Pt, Au, Al, or SnO₂). The As₂Se₂ layers had a thickness of

Card 1/4

APPROVED FOR RELEASE: 08/31/2001 CIA-RDP86-00513R001031210017-5"

67258

BOV/20-129-4-20/68 Some Specific Features of the Photoelectric Effect in Amorphous Layers of Arsenic Triselenide

0.5 to 2 μ . Onto this layer, semitransparent electrodes made from Al, Au, or Ag were applied in vacuum, so that the properties could be investigated "transversely" to the layer. The layers As 2Se 3 have an amorphous structure. The dark carriers were holes. In the course of longitudinal measurements $Q_d = 10^{11} - 10^{12}$ Ohm.om was found for the specific dark resistance, and in measurements transversal to the layer $q_d = 10^{12} - 10^{13}$ Ohm.om was found. The layers had a high photoconductivity which surpassed that of the Sb2S3 layers. In the measurements carried out along the layers no photoelectromotive force existed. However, in transversal measurements a photoelectromotive force was always observed, and it attained a value of E = 0.4 v. The photoelectric effect in the As₂Se₃ layers had low viscosity. Besides, several interesting features of the

photoelectric effect were observed in the As Se, layers, as photoelectric effect were observed in the As Se, layers, as photoelectric current and e.g. a temperature dependence of the photoelectric current and

Card 2/4

APPROVED FOR RELEASE: 08/31/2001 CIA-RDP86-00513R001031210017-5"

67258

SOV/20-129-4-20/68 Some Specific Features of the Photoelectric Effect in Amorphous Layers of Arsenic Triselenide

a spectral distribution of photoelectric sensitivity. A diagram shows the dependence of the photoconductivity logarithm and of the temperature conductivity upon the reciprocal temperature in longitudinal measurements. The dark conductivity and, at low temperatures, also photoconductivity increase exponentially with increasing temperature. At higher temperature photoconductivity decreases with increasing temperature. This may be due to the variation of the recombination conditions (increase of the recombination rate) of the current carriers. The exponential increase at low temperatures is, according to the authors' opinion, due to the "adhesion" of light-induced current carriers. The barrier mechanism and the exciton mechanism are, as the authors believe, only little probable. In transversal measurements the course of the spectral distribution curve of the photoelectric effect depends to a considerable extent on the polarity of the applied voltage. In the case of some samples the sign of the photoelectromotive force also depended on the wave length. The authors also produced samples with a common lower electrode (covered with Al) and with different upper electrodes (Al and Au). In the case of illumination coming from the direction of the

Card 3/4

APPROVED FOR RELEASE: 08/31/2001 CIA-RDP86-00513R001031210017-5"

67258

SCV/20-129-..-2 /69 Some Specific Features of the Photoelectric Effect in Amorphous Layers of Arsenic Triselenide

lower electrodes, spectral characteristics of the type I were obtained by measurements carried out on the electrodes .1 - Al, and in the case of measurements carried out on the electrodes Al - Au characteristics of the type II resulted. The authors endeavor to explain the totality of the phenomena observed by the so-called photodiode effect. There are 3 figures and 15 references, 11 of which are Soviet.

ASSOCIATION: Fiziko-tekhnicheskiy institut Akademii nauk SSSR (Institute of

Physics and Technology of the Academy of Sciences, USSE)

July 20, 1959, by A. F. Ioffe, Academician PRESENTED:

July 15, 1959 SUBMITTED:

Card 4/4

CIA-RDP86-00513R001031210017-5" APPROVED FOR RELEASE: 08/31/2001

3/181/60/002/01/12/035 B008/B011

AUTHORS:

Kolomiyets, B. T., Lyubin, V. M.

TITLE:

On the Mechanism of Photoconductivity in Amorphous

Chalcogenide Layers

Fizika tverdogo tela, 1960, Vol. 2, No. 1, pp. 52 - 54

TEXT: The authors investigated the dependences of the photocurrent on exposure at increased temperatures and the temperature course of the photocurrent in a wide exposure range on a semiconductor layer. Amorphous Sb₂S₃₋₁ and in part, As₂Se₃ layers were used for the purpose.

The results obtained can be evidently extended also to other amorphous photoconductive layers, above all, other antimony and arsenic chalcogenides. The methods applied were the same as those of Refs. 1-3. Fig. 1 illustrates typical lux-ampere characteristics of amorphous layers at different temperatures. The presence of two gradients at room temperature was explained by the assumption of two recombination mechanisms which occur in CdS samples. Fig. 2 shows typical dependences of

Card 1/2

APPROVED FOR RELEASE: 08/31/2001 CIA-RDP86-00513R001031210017-5"

On the Mechanism of Photoconductivity in Amorphous Chalcogenide Layers

S/181/60/002/01/12/035 B008/B011

the photocurrent logarithm on the inversion temperature, that were taken at different exposure values on the photoconductor. Experimental data indicate that photocurrents in amorphous photoconductive layers show two opposite tendencies with a rise in temperature. The exponential temperature dependence of the effective carrier mobility is dealt with in Refs. 9 and 10. In amorphous photoconductive layers the second mechanism described in Ref. 10 seems to prevail. This is the steplike mechanism which is characterized by a discontinuous motion of the carriers, due to their "adhesion". The investigations carried out point to a complicated mechanism of the internal photoeffect. An important conclusion reached here is that the investigation of the temperature course of the photocurrent can serve as a simple method of determining the position of the adhesion levels in amorphous photoconductive layers. V.K. Kocherov, graduate student of LGU participated in the work. A.F. Ioffe is mentioned (Ref. 10). There are 2 figures and 10 references: 4 Soviet.

ASSOCIATION:

Leningradskiy fiziko-tekhnicheskiy institut AN SSSR

(Leningrad Institute of Physics and Technology AS USSR)

SUBMITTED:

August 31, 1959

Card 2/2

APPROVED FOR RELEASE: 08/31/2001 CIA-RDP86-00513R001031210017-5"

89023

S/020/60/135/004/018/037 B019/B077

AUTHORS:

Lyubin, V. M., and Fedorova, G. A.

TITLE:

The Problem of High-voltage Photo-electromotive Forces in

Thin Semiconducting Layers

PERIODICAL:

Doklady Akademii nauk SSSR, 1960, Vol. 135, No. 4, pp. 833-836

TEXT: The authors present the results of a study of high-voltage photo-emf in layers of CdTe and of some antimony and bismuth halides. The initial material was cadmium telluride which is available as a luminescent powder under the trade-mark "chistyy" ("pure"), or is obtained by melting the necessary portions of Cd and Te. Evaporation on glass or mica was done in a graphite container. In all layers produced by this method, a photo-emf of up to 80 - 100 v/cm was established, and some layers showed values of up to 150 - 180 v/cm at room temperature. The magnitude of the photo-emf was a function of the layer thickness, the temperature of the base, and the manufacturing process. A layer thickness of d \simeq 1.5 μ and a base temperature of about 300°C were found to be most favorable; the resistivity of the layer was 10 7 - 10 8 ohm.cm. These investigations showed that CdTe can be Card 1/2

89023

The Problem of High-voltage Photo-electromotive Forces in Thin Semiconducting Layers S/020/60/135/004/018/037 B019/B077

used in television devices. It was found that the sign of the photo-emf can be different even when using equal manufacturing methods. No change of sign was established when the interval between container and base was kept small during the production. The origin of a high-voltage photo-emf is explained by a photo current which might pass through the layer during evaporation and separate the ionized impurities. Tests did not confirm this theory. In different spectral ranges different signs of photo-emf were found; and test results indicated the existence of sublayers which complicate the explanation of high-voltage photo-emf. Practically the same results were obtained for the photo-emf of binary and ternary layers of antimony and bismuth produced in the same way as the CdTe layers. There are 2 figures, 2 tables, and 8 references: 4 Soviet and 4 US.

PRESENTED: June 20, 1960, by A. F. Ioffe, Academician

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attecks Kolomiyets, B. T., and Lyubit, V. M.

TITLE Electrical and photoelectrical properties of antimoty

selenide layers

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TEXT As $_{2}$ Se $_{3}$ layers 0.4 - 5 μ thick and of 99.498 and 99.49, party were studied. They are of great interest for television-tube mark as, al. Au. Pt and SnO $_{2}$ were used as electrode materials. Industry particular to the usual methods and by the electron contact. Electron diffrantly protures taken by V. A. Dorin showed that the Asple layers obtained by condensation in vacuo were amorphous. Hole-type conductivity was predominant. Dark resistivity varied between 10.1 and 10.1 chm of all fields ℓ Ce = 10.4 v/cm Ohmes law was satisfied, above these field stress syperlinear current increase was observed. For strong fields.

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